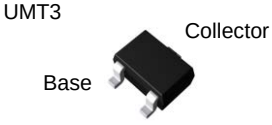
2SB1694

PNP –1A –30V Low Frequency Amplifier Transistors Datasheet

Parameter	Value
V_{CEO}	–30V
I_C	–1A

●Outline

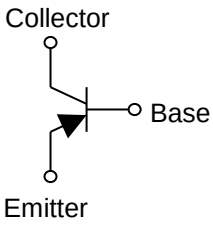


2SB1694
SOT-323 (SC-70)

●Features

1) A Collecotr current is large.General Purpose.
2) Collector saturation voltage is low.
   $V_{CE(sat)}$ is Max. –380mV
   At I_C= –500mA, I_B= –25mA
3) Complementary NPN Types :
   2SD2656
4) Lead Free/RoHS Compliant.

●Inner circuit



●Applications

Driver circuit

●Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1694	UMT3	2021	T106	180	8	3,000	ES

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●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	−30	V
Collector-emitter voltage	V_{CEO}	−30	V
Emitter-base voltage	V_{EBO}	−6	V
Collector current	I_C	−1	A
	I_{CP} *1	−2	A
Power dissipation	P_D *2	200	mW
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	−55 to +150	°C

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-emitter breakdown voltage	BV_{CEO}	I_C = −1mA	−30	-	-	V
Collector-base breakdown voltage	BV_{CBO}	I_C = −10μA	−30	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I_E = −10μA	−6	-	-	V
Collector cut-off current	I_{CBO}	V_{CB} = −30V	-	-	−100	nA
Emitter cut-off current	I_{EBO}	V_{EB} = −6V	-	-	−100	nA
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C = −500mA, I_B = −25mA	-	−180	−380	mV
DC current gain	h_{FE}	V_{CE} = −2V, I_C = −100mA *3	270	-	680	-
Transition frequency	f_T	V_{CE} = −2V, I_E = 100mA f=100MHz *3	-	320	-	MHz
Output capacitance	C_{ob}	V_{CB} = −10V, I_E = 0mA f = 1MHz	-	7	-	pF

*1 P_W=1ms Single pulse.

*2 Each terminal mounted on a reference footprint

*3 Pulsed

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●**Electrical characteristic curves**(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

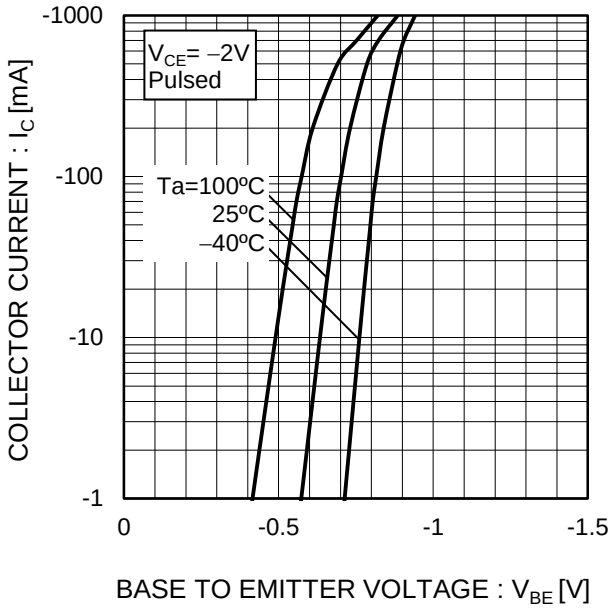


Fig.2 Typical Output Characteristics

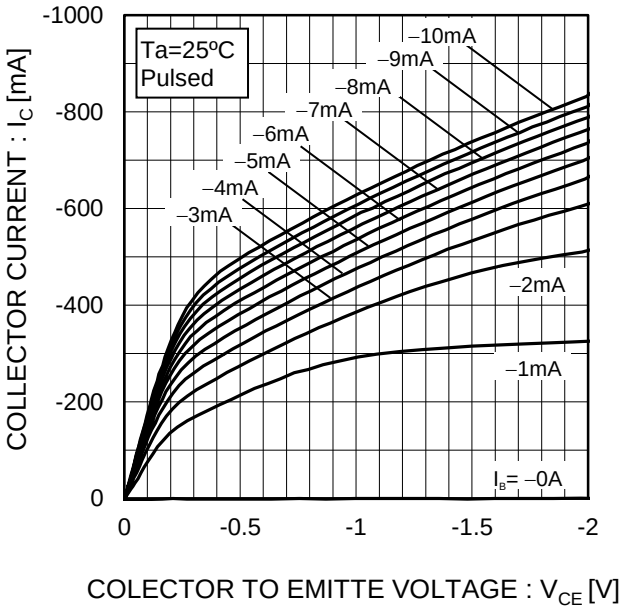


Fig.3 DC Current Gain vs. Collector Current(I)

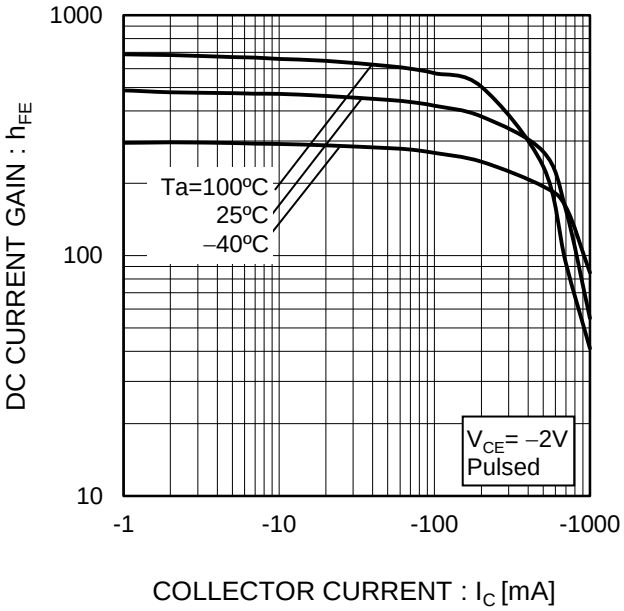
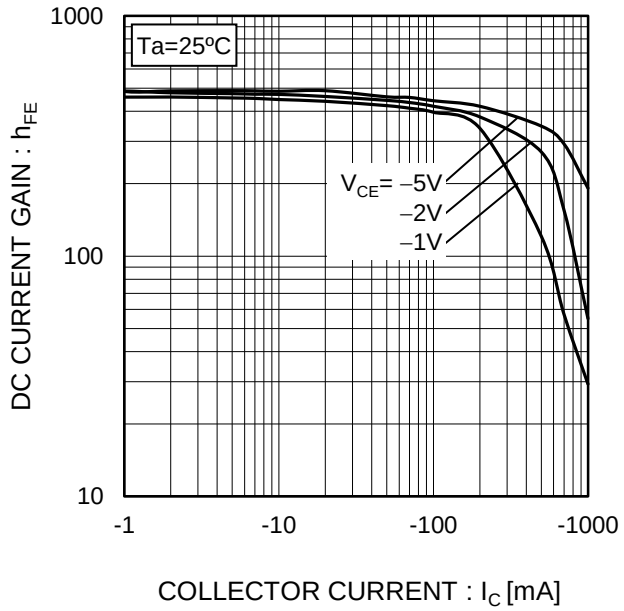


Fig.4 DC Current Gain vs. Collector Current(II)



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●**Electrical characteristic curves**(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

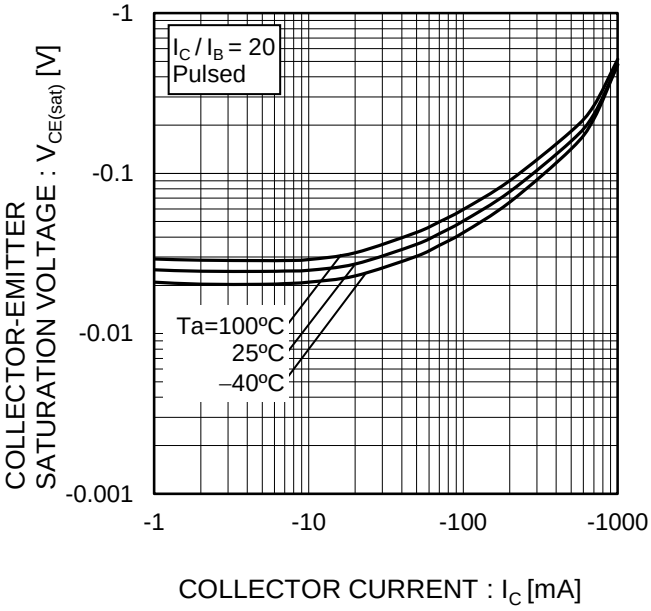


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

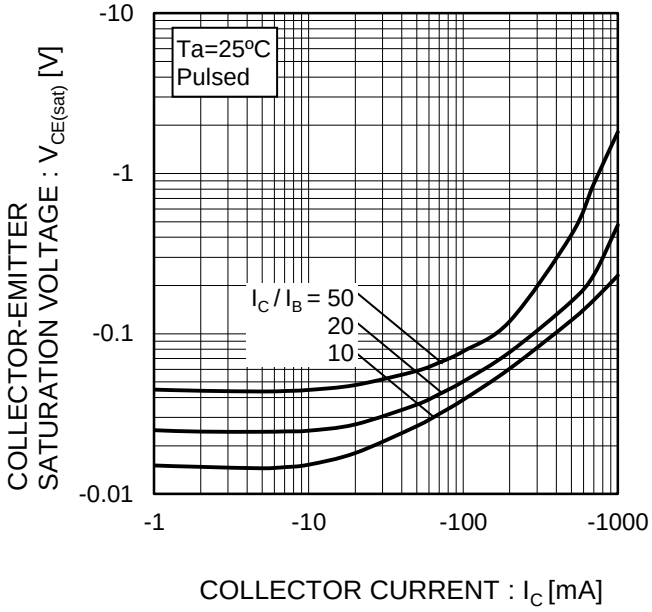


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

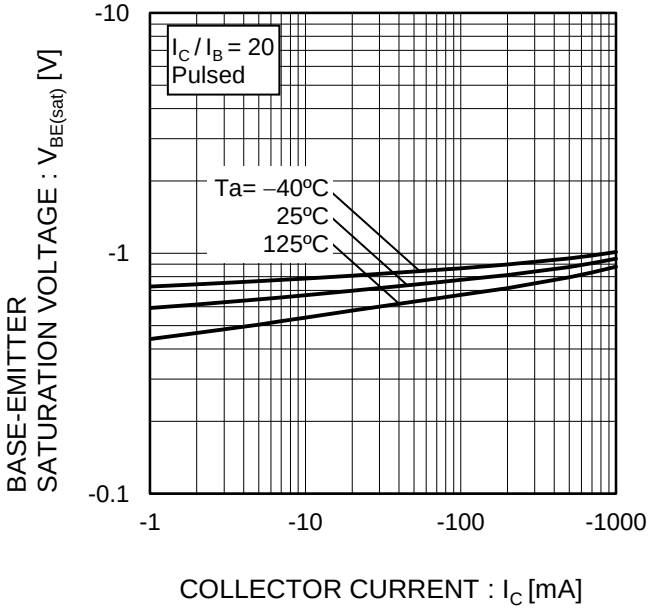
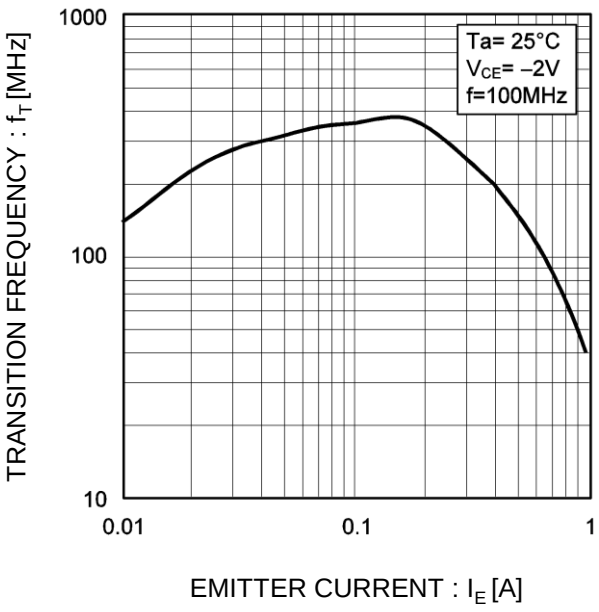


Fig.8 Gain Bandwidth Product vs. Emitter Current



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●**Electrical characteristic curves**(Ta = 25°C)

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage
Collector output capacitance vs. Collector-Base Voltage

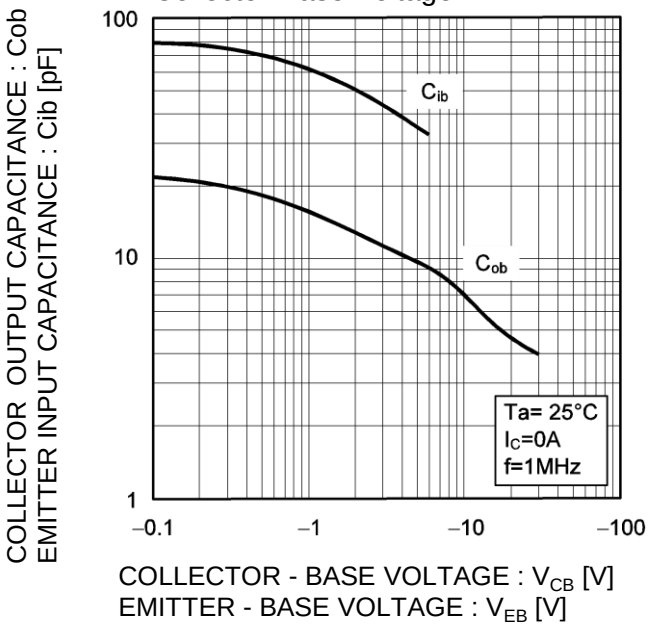
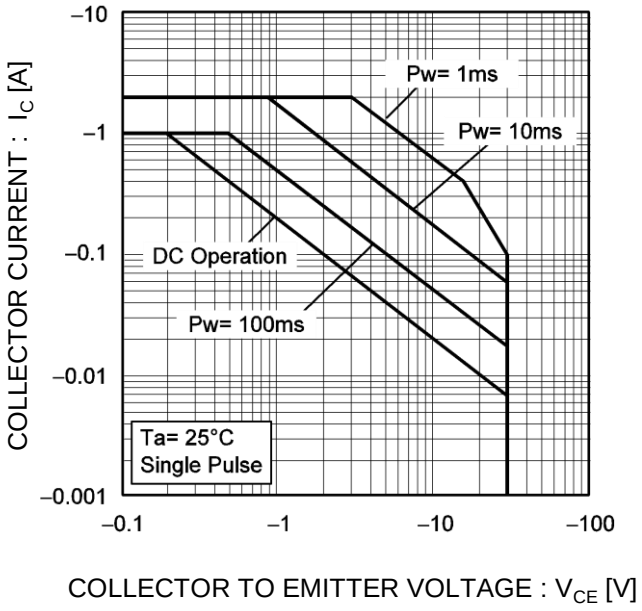


Fig.10 Safe Operating Area



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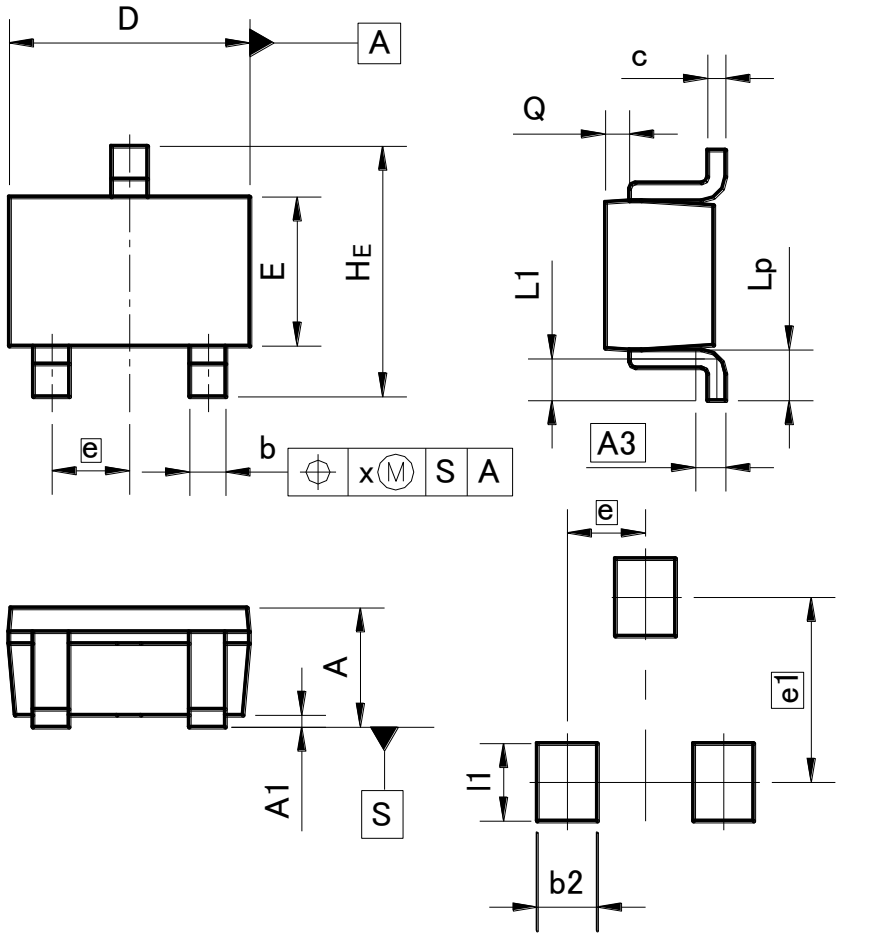
●**Dimensions** (Unit : mm)

UMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	−	0.10	−	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	−	0.50	−	0.020
e1	1.55		0.061	
l1	−	0.65	−	0.026

Dimension in mm / inches

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